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SERIAL NUMBER 10/512,022	FILING OR 371(c) DATE 10/19/2004 RULE	CLASS 117	GROUP ART UNIT 1765	ATTORNEY DOCKET NO. 93120	
APPLICANTS Tetsuhiro Iida, Hiratsuka-shi, JAPAN; Yutaka Shiraishi, Hiratsuka-shi, JAPAN; Ryota Suewaka, Hiratsuka-shi, JAPAN; Junsuke Tomioka, Hiratsuka-shi, JAPAN;					
** CONTINUING DATA ***** This application is a 371 of PCT/JP03/04868 04/17/2003					
** FOREIGN APPLICATIONS ***** JAPAN 2002-118281 04/19/2002					
Foreign Priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Allowance Verified and Acknowledged <u>Examiner's Signature</u> <u>Initials</u>		STATE OR COUNTRY JAPAN	SHEETS DRAWING 8	TOTAL CLAIMS 16	INDEPENDENT CLAIMS 7
ADDRESS 24628					
TITLE Single crystal silicon producing method, single crystal silicon wafer producing method, seed crystal for producing single crystal silicon, single crystal silicon ingot, and single crystal silicon wafer					
FILING FEE RECEIVED 1432	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		